Vishay Semiconductors

Hyperfast Rectifier, 60 A FRED Pt[®] Gen 5



www.vishay.com

PRIMARY CHARACTERISTICS							
I _{F(AV)} 60 A							
V _R	1200 V						
V _F at I _F at 125 °C	2.1 V						
t _{rr}	30 ns						
T _J max.	175 °C						
Package	TO-247AD 2L						
Circuit configuration	Single						

FEATURES

- Hyperfast and optimized Qrr
- Best in class forward voltage drop and switching losses trade off
- Optimized for high speed operation
- 175 °C maximum operating junction temperature
- Polyimide passivation
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for high frequency converters, both soft switched / resonant. Specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Repetitive peak reverse voltage	V _{RRM}		1200	V				
Average rectified forward current	I _{F(AV)}	T _C = 105 °C, D = 0.50	60					
Non-repetitive peak surge current	I _{FSM}	$T_C = 45$ °C, $t_p = 10$ ms, sine wave	420	А				
Repetitive peak forward current	I _{FRM}	T _C = 105 °C, D = 0.50, f = 20 kHz	120					
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C				

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL TEST CONDITIONS			TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	1200	-	-			
	¥-	I _F = 60 A	-	2.6	3.15	V		
Forward voltage	V _F	I _F = 60 A, T _J = 125 °C	-	2.1	-			
Reverse leakage current	I _R	$V_{R} = V_{R}$ rated	-	-	50	μA		
neverse leakage current		$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500	μΑ		
Junction capacitance	C _T V _R = 200 V		-	32	-	pF		
Series inductance	L _S	Measured to lead 5 mm from package body	-	8	-	nH		

Pb-free

RoHS COMPLIANT HALOGEN FREE



Vishay Semiconductors

DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS				
		I _F = 1.0 A, dI _F /dt =	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}, V_R = 30 \text{ V}$			-				
Reverse recovery time	t _{rr}	T _J = 25 °C		-	120	-	ns			
		T _J = 125 °C		-	170	-				
Peak recovery current		T _J = 25 °C	$I_F = 40 \text{ A}$	-	17	-	A			
Peak recovery current	I _{RRM}	T _J = 125 °C	dI _F /dt = 600 A/µs V _R = 400 V	-	32	-				
	Q _{rr}	T _J = 25 °C		-	970	-	nC			
Reverse recovery charge		T _J = 125 °C		-	2950	-				
Reverse recovery time	1	T _J = 25 °C		-	90	-	ns			
Reverse recovery time	t _{rr}	T _J = 125 °C		-	130	-				
Poak receivery ourrent	I _{RRM}	T _J = 25 °C	I _F = 60 A dI _F /dt = 1000 A/μs	-	32	-	A			
Peak recovery current		T _J = 125 °C	$V_{\rm R} = 800 \rm V$	-	53	-				
	0	T _J = 25 °C	1	-	1570	-				
Reverse recovery charge	Q _{rr}	T _J = 125 °C	1	-	4300	-	nC			

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER SYMBOL TEST CONDITIONS MIN. TYP. MAX. UNITS										
Thermal resistance, junction-to-case	R _{thJC}		-	-	0.4	°C/W				
Weight			-	5.5	-	g				
Weight			-	0.2	-	oz.				
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)				
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C				
Marking device		Case style: TO-247AD 2L	E5PX6012L							

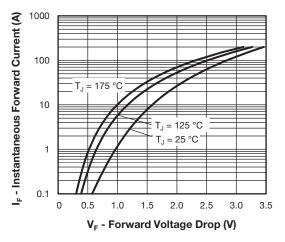


Fig. 1 - Typical Forward Voltage Drop Characteristics

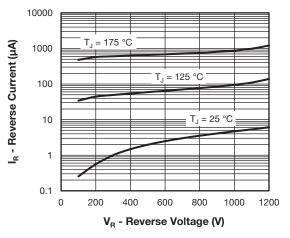


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFI Downloaded From <u>Oneyac.com</u> <u>w.vishay.com/doc?91000</u>

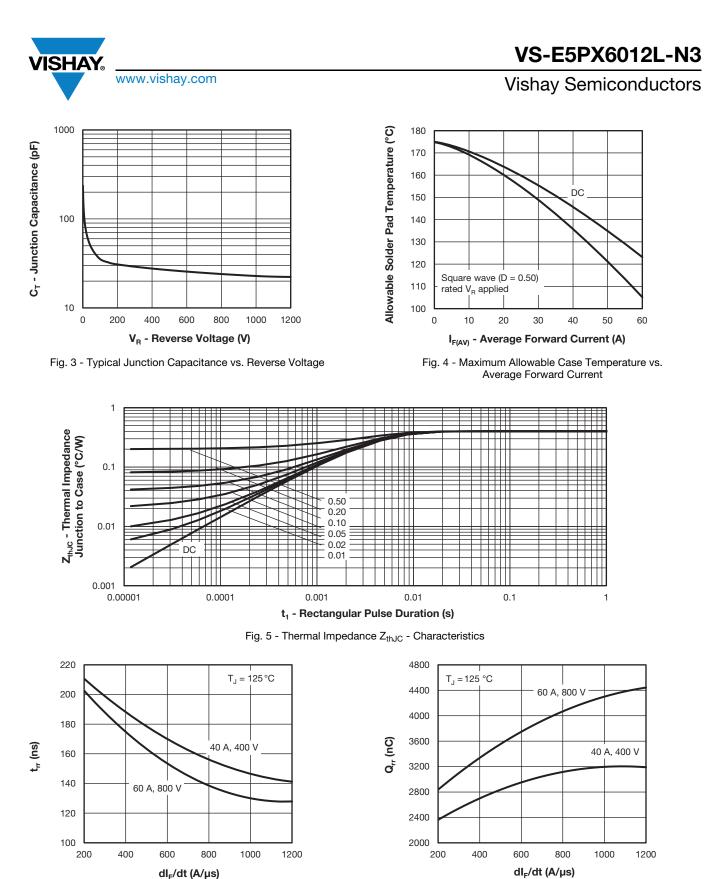


Fig. 6 - Typical Reverse Recovery Time vs. dl_F/dt

Document Number: 96479

For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFI Downloaded From Oneyac.com

VS-E5PX6012L-N3

Vishay Semiconductors



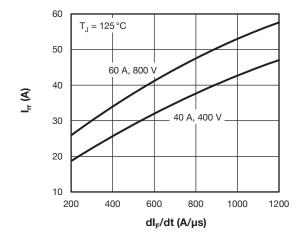


Fig. 8 - Typical Recovery Current vs. dl_F/dt

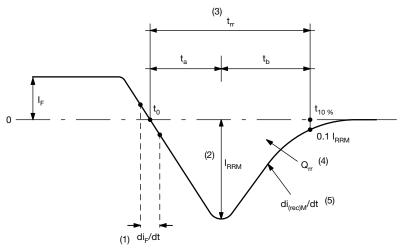


Fig. 9 - Reverse Recovery Waveform and Definitions

Notes

- $^{(1)}$ di_F/dt rate of change of current through zero crossing
- ⁽²⁾ I_{RBM} peak reverse recovery current
- $^{(3)}$ t_{rr} reverse recovery time measured from t₀, crossing point of negative going I_F, to point t_{10%}, 0.1 I_{RRM}
- $^{(4)}~~\text{Q}_{rr}$ area under curve defined by t_0 and $t_{10}~\%$

$$Q_{rr} = \int_{t_0}^{t_{10}\%} I(t)dt$$

 $^{(5)}$ di_(rec)M/dt - peak rate of change of current during t_b portion of t_{rr}

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-E5PX6012L-N3	25	500	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS						
www.vishay.com/doc?95536						
www.vishay.com/doc?95648						
www.vishay.com/doc?96556						

Revision: 30-Jul-2018

Document Number: 96479

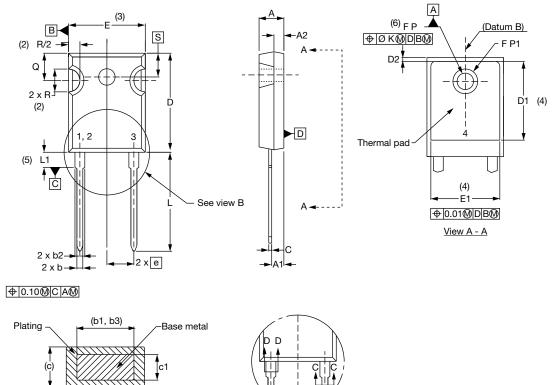
For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFI Downloaded From Oneyac.com



Vishay Semiconductors

TO-247AD 2L

DIMENSIONS in millimeters and inches



Section C - C, D - D

MILLIMET

ľ

MIN.

4.65

2.21

1.50 0.99

0.99

1.65

1.65

0.38 0.38

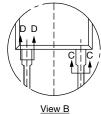
19.71

13.08

0.51

(b, b2)

(4)



TERS	INCHES		NOTES		CVMDOL	MILLIN	IETERS	INC	HES	NOTES
MAX.	MIN.	MAX.	NUTES	SYMBOL		MIN.	MAX.	MIN.	MAX.	NUTES
5.31	0.183	0.209			E	15.29	15.87	0.602	0.625	3
2.59	0.087	0.102			E1	13.46	-	0.53	-	
2.49	0.059	0.098			е	e 5.46 BSC 0.215 BSC		BSC		
1.40	0.039	0.055			ØK	0.254		0.010		
1.35	0.039	0.053			L	19.81	20.32	0.780	0.800	
2.39	0.065	0.094			L1	3.71	4.29	0.146	0.169	
2.34	0.065	0.092			ØР	3.56	3.66	0.14	0.144	
0.89	0.015	0.035			Ø P1	-	6.98	-	0.275	
0.84	0.015	0.033			Q	5.31	5.69	0.209	0.224	
20.70	0.776	0.815	3		R	4.52	5.49	0.178	0.216	
-	0.515	-	4		S	5.51 BSC		0.217	BSC	

Notes

SYMBOL

A A1

A2

b

b1 b2

b3

С

c1 D

D1

D2

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

1.35

0.020

0.053

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body

(4) Thermal pad contour optional with dimensions D1 and E1

(5) Lead finish uncontrolled in L1

(6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

Revision: 28-May-2018 Document Number: 95536 1 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFI Downloaded From Oneyac.com w.vishay.com/doc?91000



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.



单击下面可查看定价,库存,交付和生命周期等信息

>>Vishay(威世)